

Silicon Standard Recovery Diode

$V_{RRM} = 600\text{ V} - 1200\text{ V}$

$I_F = 150\text{ A}$

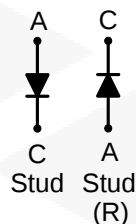
Features

- High Surge Capability
- Types from 600 V to 1200 V V_{RRM}
- Not ESD Sensitive

Note:

1. Standard polarity: Stud is cathode.
2. Reverse polarity (R): Stud is anode.
3. Stud is base.

DO-8 Package



Maximum ratings, at $T_j = 25\text{ }^{\circ}\text{C}$, unless otherwise specified ("R" devices have leads reversed)

Parameter	Symbol	Conditions	S150J (R)	S150K (R)	S150M (R)	S150Q (R)	Unit
Repetitive peak reverse voltage	V_{RRM}		600	800	1000	1200	V
RMS reverse voltage	V_{RMS}		420	560	700	840	V
DC blocking voltage	V_{DC}		600	800	1000	1200	V
Continuous forward current	I_F	$T_C \leq 180\text{ }^{\circ}\text{C}$	150	150	150	150	A
Surge non-repetitive forward current, Half Sine Wave	$I_{F,SM}$	$T_C = 25\text{ }^{\circ}\text{C}$, $t_p = 8.3\text{ ms}$	3140	3140	3140	3140	A
Operating temperature	T_j		-55 to 150	-55 to 150	-55 to 150	-55 to 150	$^{\circ}\text{C}$
Storage temperature	T_{stg}		-55 to 150	-55 to 150	-55 to 150	-55 to 150	$^{\circ}\text{C}$

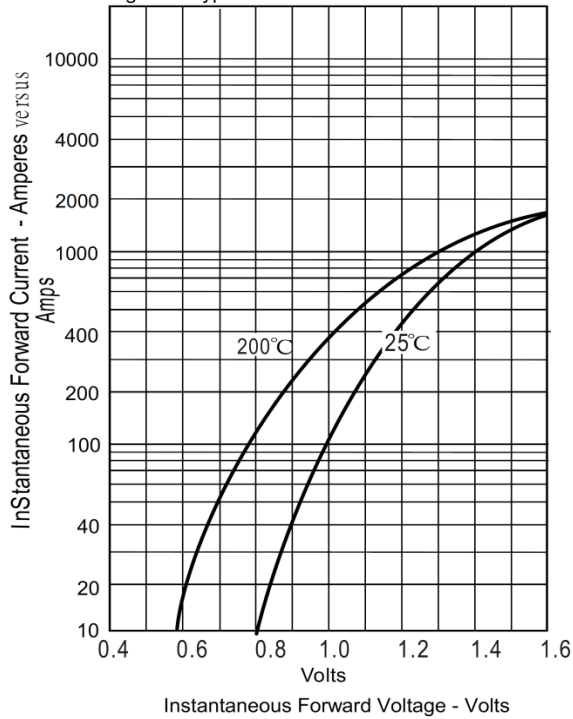
Electrical characteristics, at $T_j = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Symbol	Conditions	S150J (R)	S150K (R)	S150M (R)	S150Q (R)	Unit
Diode forward voltage	V_F	$I_F = 150\text{ A}$, $T_j = 25\text{ }^{\circ}\text{C}$	1.2	1.2	1.2	1.2	V
Reverse current	I_R	$V_R = 600\text{ V}$, $T_j = 25\text{ }^{\circ}\text{C}$	10	10	10	10	μA
		$V_R = 600\text{ V}$, $T_j = 150\text{ }^{\circ}\text{C}$	15	15	15	9	mA

Thermal characteristics

Thermal resistance, junction - case	R_{thJC}		0.35	0.35	0.35	0.35	$^{\circ}\text{C/W}$
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Figure.1-Typical Forward Characteristics



Figur.2-Forward Derating Curve

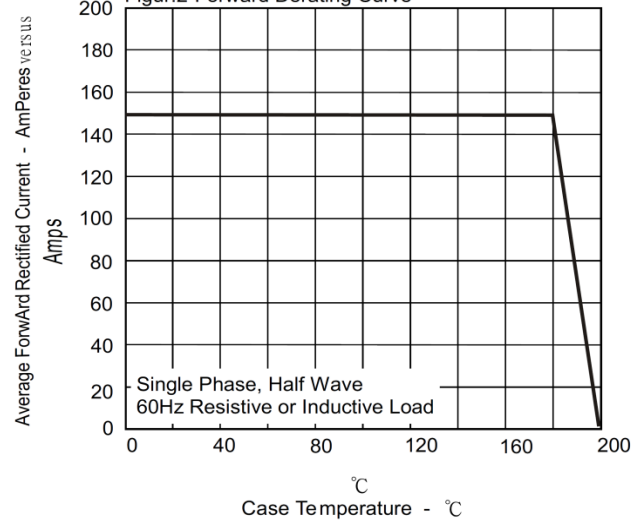
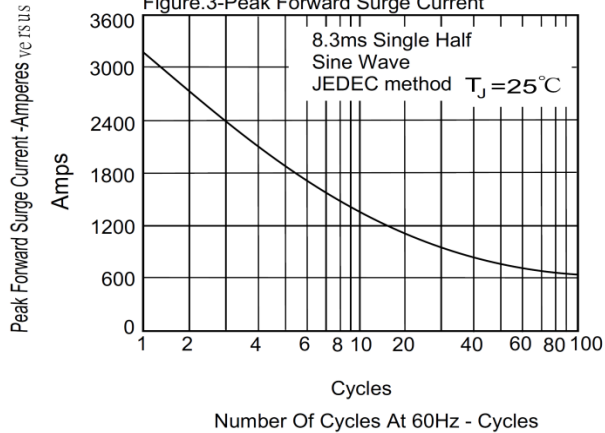
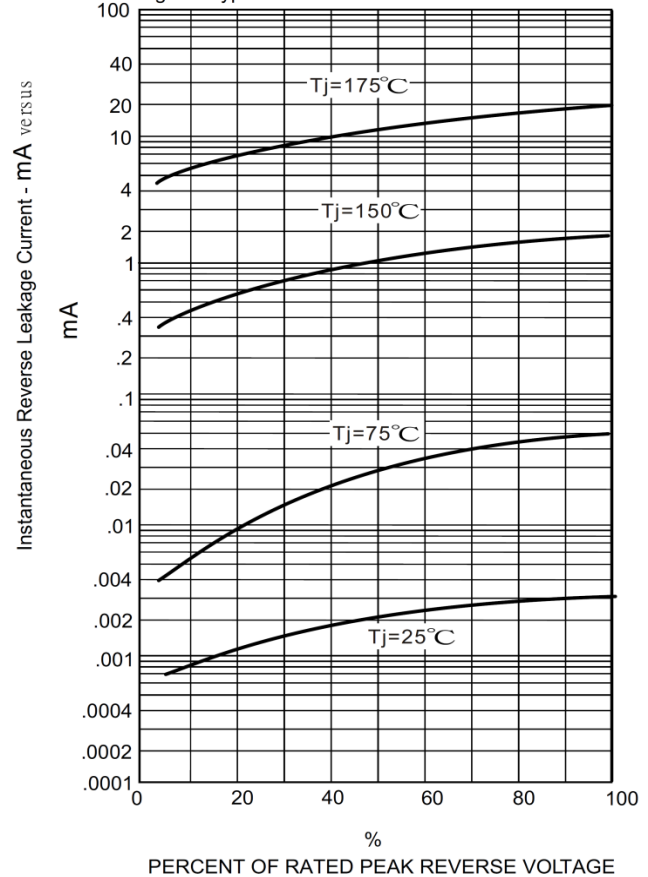


Figure.3-Peak Forward Surge Current



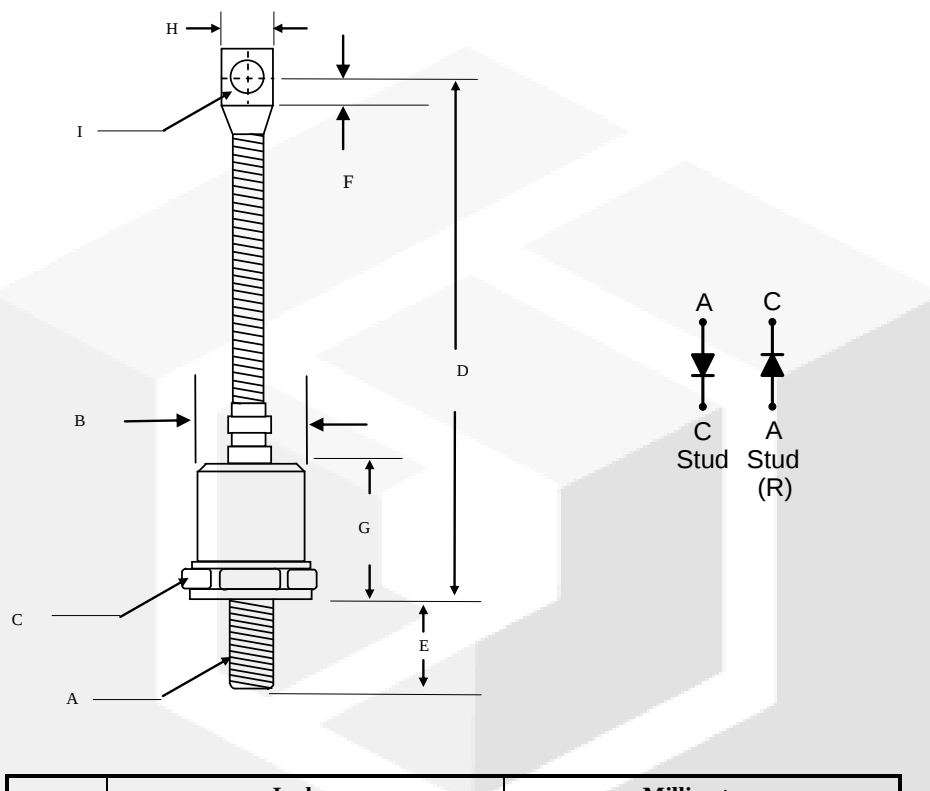
Figur.4-Typical Reverse Characteristics



Package dimensions and terminal configuration

Product is marked with part number and terminal configuration.

DO-8 (DO-205AA)



	Inches		Millimeters	
	Min	Max	Min	Max
A	3/8-24 UNF			
B	-----	φ0.930	-----	φ23.5
C	1.050	1.060	26.67	26.92
D	4.300	4.700	109.22	119.38
E	-----	0.690	-----	17.00
F	0.260	-----	6.50	-----
G	-----	0.940	-----	24.00
H	-----	0.600	-----	15.23
I	0.276	0.286	7.010	7.260

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